

DOCKET NO: 251265US2RD DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
MASAYUKI ISHIKAWA ET AL :  
SERIAL NO: NEW DIVISIONAL :  
APPLICATION :  
FILED: HEREWITH :  
FOR: SEMICONDUCTOR DEVICE, :  
SEMICONDUCTOR LASER, THEIR :  
MANUFACTURING METHODS AD :  
ETCHING METHODS

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified divisional application as follows:

**Amendment to the Specification** begins on page 2.

**Amendments to the Claims** begin on page 3 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.